	Туре	L #	Hits	Search Text	DBs
1	IS&R	L1	1	("6639827").PN.	US-PGPUB; USPAT
2	BRS	L2	13954	latch.clm.	US-PGPUB
3	BRS	L3	1703	2 and transistor\$1.clm.	US-PGPUB
4	BRS	L4	35	3 and gate adj oxide.clm.	US-PGPUB
5	IS&R	L5	685	(327/202-203).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
6	IS&R	L6	1108	(327/206-208).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
7	IS&R	L7	591	(327/210-212).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB
8	IS&R	L8	361	(327/218).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB